



#### **Product Summary**

V <sub>(BR)DSS</sub>	Rds(on)	Ι <sub>D</sub> T <sub>A</sub> = +25°C
100V	6.0Ω @ V <sub>GS</sub> = 10V	170mA

#### Description

MOSFET is designed This to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### Applications

- Small Servo Motor Control
- Power MOSFET Gate Drivers
- Switching Applications

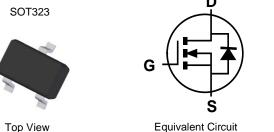
## N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features**

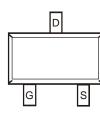
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- High Drain-Source Voltage Rating
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208(e3)
- Weight: 0.006 grams (Approximate)



Equivalent Circuit



Top View

## Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
BSS123W-7-F	Standard	SOT323	3000/Tape & Reel

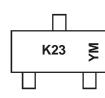
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



K23 = Product Type Marking Code YM = Date Code MarkingY or  $\overline{Y} = Year (ex: A = 2013)$ M = Month (ex: 9 = September)

Date Code Kev

Date Coue	Rey													
Year	2002	2003	2004	2005	2006		2012	2013	2014	2015	2016	2017	2018	2019
Code	Ν	Р	R	S	Т		Z	А	В	С	D	Е	F	G
Month	Jan	Feb	M	ar	Apr	Мау	Jun	Jul	Aug	Se	р (	Oct	Nov	Dec
Code	1	2	3	3	4	5	6	7	8	9		0	Ν	D



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characte	eristic	Symbol	Value	Units
Drain-Source Voltage		V <sub>DSS</sub>	100	V
Drain-Gate Voltage $R_{GS} \le 20K\Omega$		V <sub>DGR</sub>	100	V
Gate-Source Voltage	Continuous	V <sub>GSS</sub>	±20	V
Drain Current (Note 5)	Continuous Pulsed	I <sub>D</sub> IDM	170 680	mA

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	Cymbol		TYP	Max	Unit	Test condition
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100			V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA
Zero Gate Voltage Drain Current	IDSS	_	_	1.0 10	μA nA	$V_{DS} = 100V, V_{GS} = 0V$ $V_{DS} = 20V, V_{GS} = 0V$
Gate-Body Leakage, Forward	IGSSF			50	nA	$V_{GS} = 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)			•	•	•	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.8	1.4	2.0	V	$V_{DS} = V_{GS}, I_D = 1mA$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>			6.0 10	Ω	$V_{GS} = 10V, I_D = 0.17A$ $V_{GS} = 4.5V, I_D = 0.17A$
Forward Transconductance	<b>g</b> fs	80	370		mS	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.17A, f = 1.0KHz
Drain-Source Diode Forward Voltage	V <sub>SD</sub>		0.84	1.3	V	$V_{GS} = 0V, I_{S} = 0.34A$
DYNAMIC CHARACTERISTICS (Note 7)			•	•	•	
Input Capacitance	Ciss	_	29	60	pF	
Output Capacitance	Coss	_	10	15	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	2	6	pF	
SWITCHING CHARACTERISTICS(Note 7)	•		•	•	•	·
Turn-On Rise Time	tr	_	_	8	ns	
Turn-Off Fall Time	t <sub>f</sub>			16	ns	$V_{DD} = 30V, I_D = 0.28A,$
Turn-On Delay Time	t <sub>D(ON)</sub>			8	ns	$R_{GEN} = 6.0\Omega, V_{GS} = 10V$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_		13	ns	

5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com. 6. Short duration pulse test used to minimize self-heating effect. Notes:

7. Guaranteed by design. Not subject to production testing.



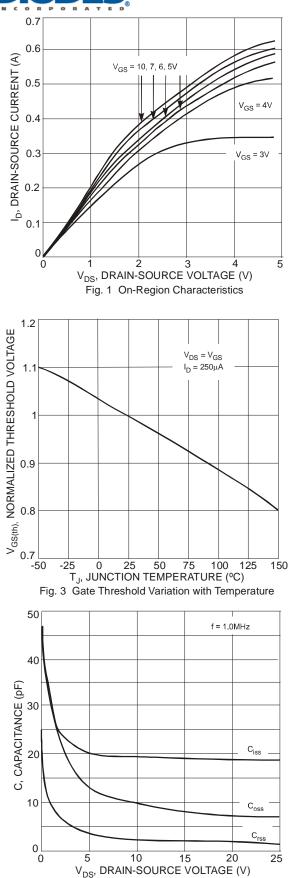
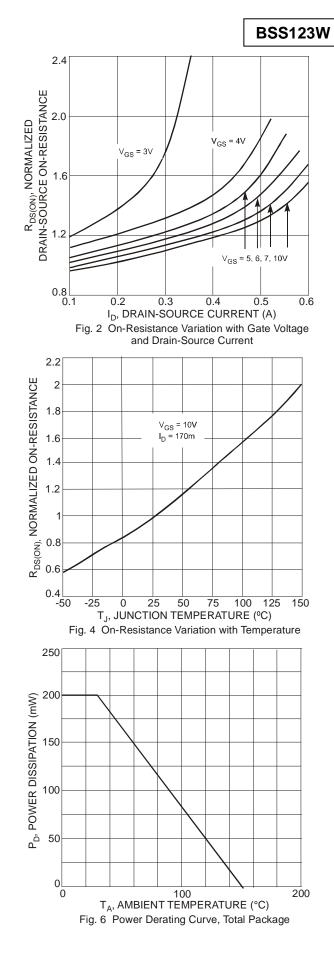


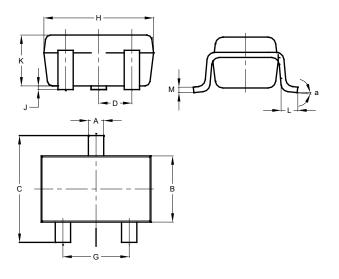
Fig. 5 Typical Capacitance





# Package Outline Dimensions

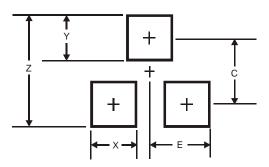
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
в	1.15	1.35	1.30			
с	2.00	2.20	2.10			
D	0	.650 BS	С			
F	0.375	0.375 0.475 0.42				
G	1.20	1.40	1.30			
н	1.80	2.20	2.15			
J	0.00 0.10 0.0					
κ	0.90	0.90 1.00 0.9				
L	0.25 0.40 0.3					
Μ	0.10	0.18	0.11			
а	8°C					
All I	Dimens	ions in	mm			

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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